NSN 5961-01-455-7084

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-455-7084 **Internal Configuration:** Field effect **Channel Polarity And Control Type (non-core):** P-channel insulated gate type **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal Voltage Rating In Volts Per Characteristic: -60.0 drain to source voltage **Current Rating Per Characteristic:** -2.00 amperes zero-gate-voltage source current any acceptable **Power Rating Per Characteristic:** 1.3 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 8 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No Fiig: A110a0